

MOSFETs Silicon P-Channel MOS (U-MOSVI)

TPCA8120

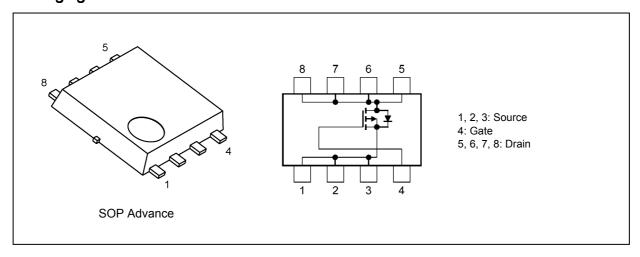
1. Applications

- · Lithium-Ion Secondary Batteries
- · Power Management Switches

2. Features

- (1) Small footprint due to a small and thin package
- (2) Low drain-source on-resistance: $R_{DS(ON)} = 2.4 \text{ m}\Omega$ (typ.) ($V_{GS} = -10 \text{ V}$)
- (3) Low leakage current: $I_{DSS} = -10 \mu A \text{ (max) (V}_{DS} = -30 \text{ V)}$
- (4) Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_D = -1 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (Ta = 25 °C unless otherwise specified)

| Characteris | tics | | Symbol | Rating | Unit |
|-------------------------------|--------------------------|----------|------------------|------------|------|
| Drain-source voltage | | | V _{DSS} | -30 | V |
| Gate-source voltage | | | V _{GSS} | -25/+20 | 1 |
| Drain current (DC) | | (Note 1) | I _D | -45 | Α |
| Drain current (pulsed) | | (Note 1) | I _{DP} | -135 | 1 |
| Power dissipation | (T _c = 25 °C) | | P _D | 45 | W |
| Power dissipation | (t = 10 s) | (Note 2) | P _D | 2.8 | W |
| Power dissipation | (t = 10 s) | (Note 3) | P _D | 1.6 | W |
| Single-pulse avalanche energy | | (Note 4) | E _{AS} | 263 | mJ |
| Avalanche current | | | I _{AR} | -45 | Α |
| Channel temperature | | | T _{ch} | 150 | °C |
| Storage temperature | | | T _{stg} | -55 to 150 | 1 |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production



5. Thermal Characteristics

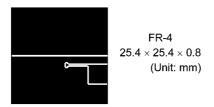
| Characteristics | | | Symbol | Max | Unit |
|---------------------------------------|--------------------------|----------|-----------------------|------|------|
| Channel-to-case thermal resistance | (T _c = 25 °C) | | R _{th(ch-c)} | 2.78 | °C/W |
| Channel-to-ambient thermal resistance | (t = 10 s) | (Note 2) | R _{th(ch-a)} | 44.6 | °C/W |
| Channel-to-ambient thermal resistance | (t = 10 s) | (Note 3) | R _{th(ch-a)} | 78.1 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: V_{DD} = -24 V, T_{ch} = 25 °C (initial), L = 0.1 mH, R_G = 25 Ω , I_{AR} = -45 A



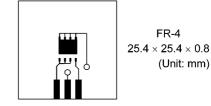


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

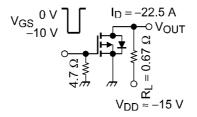
6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|----------------------|--|------|------|------|------|
| Gate leakage current | I _{GSS} | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±0.1 | μΑ |
| Drain cut-off current | I _{DSS} | $V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$ | | | -10 | |
| Drain-source breakdown voltage | V _{(BR)DSS} | $I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$ | -30 | | | V |
| Drain-source breakdown voltage (Note 5) | V _{(BR)DSX} | I _D = -10 mA, V _{GS} = 10 V | -21 | _ | | |
| Gate threshold voltage | V_{th} | $V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$ | -0.8 | _ | -2.0 | |
| Drain-source on-resistance | R _{DS(ON)} | V _{GS} = -4.5 V, I _D = -22.5 A | _ | 3.1 | 4.0 | mΩ |
| | | V_{GS} = -10 V, I_D = -22.5 A | | 2.4 | 3.0 | |

Note 5: If a forward bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics (T_a = 25 °C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|------------------|---|-----|------|-----|------|
| Input capacitance | C _{iss} | V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz | _ | 7420 | _ | pF |
| Reverse transfer capacitance | C _{rss} | | _ | 1180 | _ | |
| Output capacitance | C _{oss} | | _ | 1440 | _ | |
| Switching time (rise time) | t _r | See Fig. 6.2.1. | _ | 10 | _ | ns |
| Switching time (turn-on time) | t _{on} | | _ | 18 | _ | |
| Switching time (fall time) | t _f | | _ | 262 | _ | |
| Switching time (turn-off time) | t _{off} | | _ | 762 | _ | |



Duty \leq 1%, $t_W=10~\mu s$

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25 °C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Qg | $V_{DD} \approx -24 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -45 \text{ A}$ | _ | 190 | | nC |
| Gate-source charge 1 | Q _{gs1} | | _ | 23 | | |
| Gate-drain charge | Q_{gd} | | _ | 47 | | |

6.4. Source-Drain Characteristics (T_a = 25 °C unless otherwise specified)

| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|----------|------------------|--|-----|------|------|------|
| Reverse drain current (pulsed) | (Note 6) | I _{DRP} | _ | _ | _ | -135 | Α |
| Diode forward voltage | | V _{DSF} | I _{DR} = -45 A, V _{GS} = 0 V | _ | _ | 1.2 | V |

Note 6: Ensure that the channel temperature does not exceed 150 $^{\circ}\text{C}$.



7. Marking

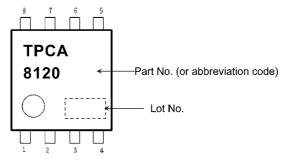


Fig. 7.1 Marking

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8. Characteristics Curves (Note)

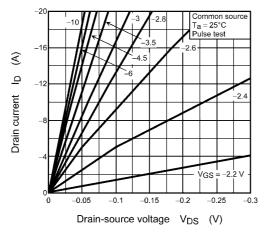


Fig. 8.1 I_D - V_{DS}

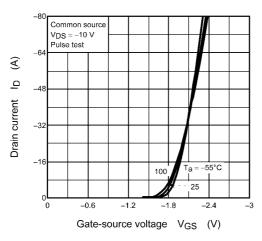


Fig. 8.3 I_D - V_{GS}

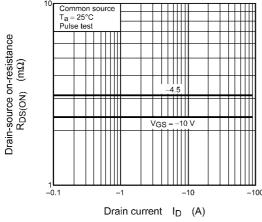


Fig. 8.5 R_{DS(ON)} - I_D

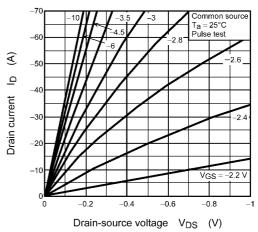


Fig. 8.2 I_D - V_{DS}

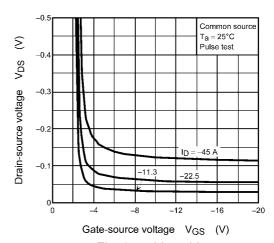


Fig. 8.4 V_{DS} - V_{GS}

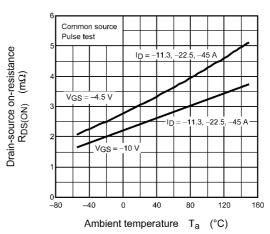
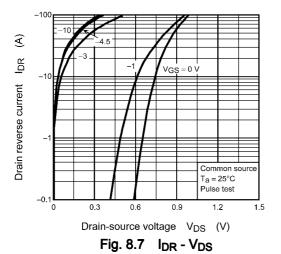
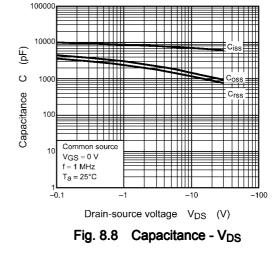
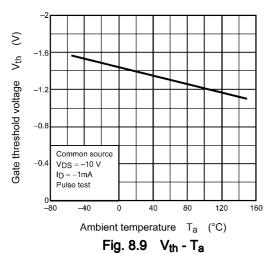


Fig. 8.6 R_{DS(ON)} - T_a







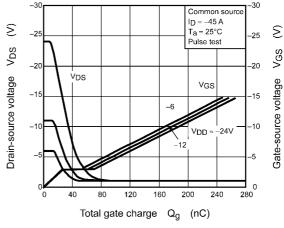
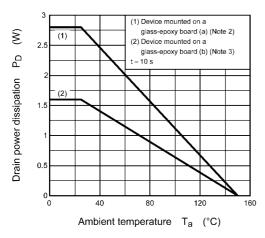


Fig. 8.10 Dynamic Input/Output Characteristics



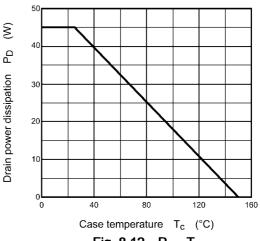


Fig. 8.11 P_D - T_a (Guaranteed Maximum)

Fig. 8.12 P_D - T_c (Guaranteed Maximum)

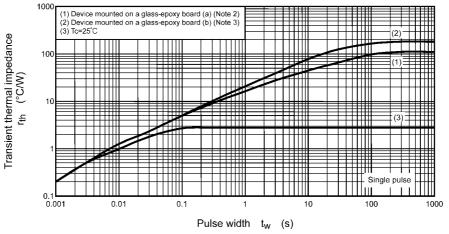


Fig. 8.13 r_{th} - t_w (Guaranteed Maximum)

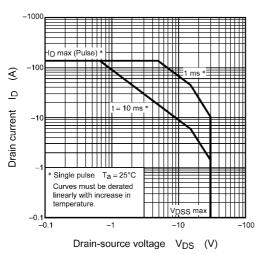


Fig. 8.14 Safe Operating Area (Guaranteed Maximum)

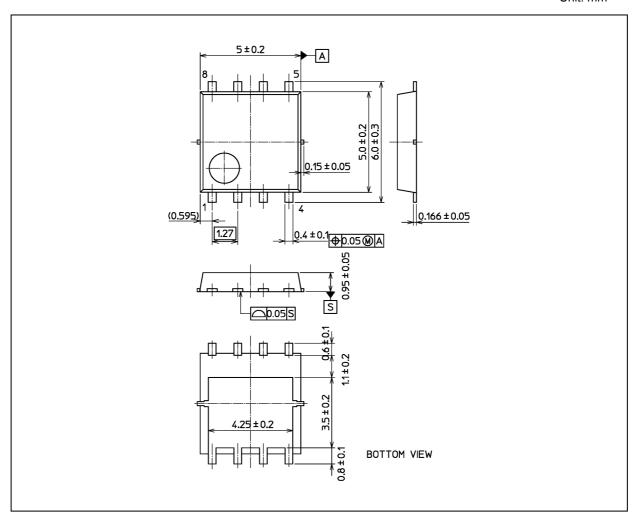
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Rev.2.0



Package Dimensions

Unit: mm



Weight: 0.069 g (typ.)

| F | Package Name(s) |
|-----------------------|-----------------|
| TOSHIBA: 2-5Q1S | |
| Nickname: SOP Advance | |



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